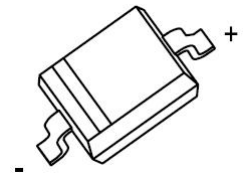
TESD4V5D3U

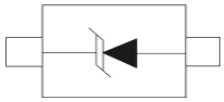
Uni-directional TVS Diode for ESD Protection

FEATURES

- ✧ 1500 Watts peak pulse power per line (t_P=8/20μs)
- ✧ Solid-state silicon-avalanche technology
- ✧ Protects one uni-directional I/O line
- ✧ Low clamping voltage
- ✧ Working voltage:4.5V
- ✧ Low leakage current
- ✧ High surge capability
- ✧ RoHS compliant

SOD-323





Pin Configuration

MAIN APPLICATIONS

- ✧ Cell phone handsets and accessories
- ✧ Microprocessor based equipment
- ✧ Personal digital assistants (PDA's)
- ✧ Notebooks, desktops, and servers
- ✧ Portable instrumentation
- ✧ Power lines
- ✧ Peripherals

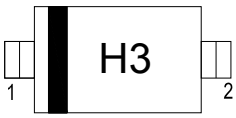
PROTECTION SOLUTION TO MEET

- ✧ IEC61000-4-2 (ESD) ±30kV (air), ±30kV (contact)
- ✧ IEC61000-4-4 (EFT) 40A (5/50ns)
- ✧ IEC61000-4-5 (Lightning) 100A (8/20μs)

MECHANICAL CHARACTERISTICS

- ✧ SOD-323 package
- ✧ Molding compound flammability rating : UL 94V-0
- ✧ Quantity per reel : 3,000pcs
- ✧ Lead finish : lead free

MARKING : H3



ORDERING INFORMATION

PART No.	PACKAGE TYPE	QUANTITY(PCS) REEL	DESCIPTION
TESD4V5D3U	SOD-323	3,000	7 inch reel pack

ABSOLUTE MAXIMUM RATINGS (T_A=25ºC, RH=45%-75%, unless otherwise noted)

Parameter	Symbol	Value	Unit
Peak pulse power dissipation on 8/20μs waveform	P_{PP}	1500	W
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V_{ESD}	+/- 30 +/- 30	kV
Lead soldering temperature	T_L	260 (10 sec.)	℃
Operating junction temperature range	T_J	-55 to +125	℃
Storage temperature range	T_{STG}	-55 to +150	℃

ELECTRICAL CHARACTERISTICS (T_A=25℃)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse working voltage	V_{RWM}				4.5	V
Reverse breakdown voltage	V_{BR}	I_T =1mA	5		7	V
Reverse leakage current	I_R	V_{RWM} =4.5V			200	nA
Peak pulse current	I_{PP}	t_P =8/20μs			100	A
Clamping voltage	V_C	I_{PP}=100A, t_P=8/20μs			15	V
Junction capacitance	C_J	V_{RWM}=0V, f=1MHz		700		pF

RATINGS AND V-I CHARACTERISTICS CURVES (T_A=25ºC, unless otherwise noted)

FIG.1:V- I curve characteristics (Uni-directional)

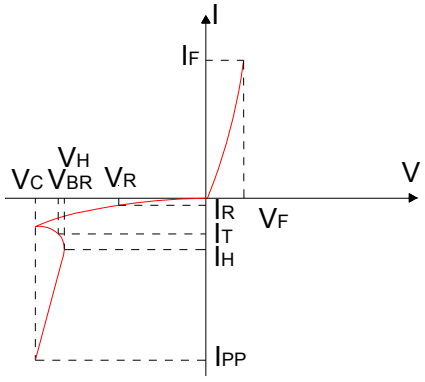


FIG.2: Pulse waveform (8/20μs)

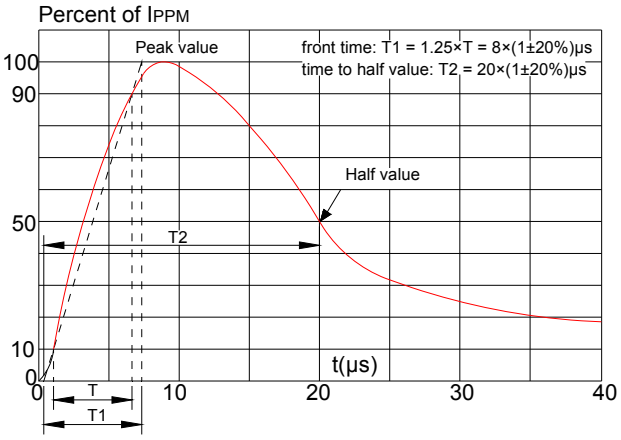


FIG.3: Pulse derating curve

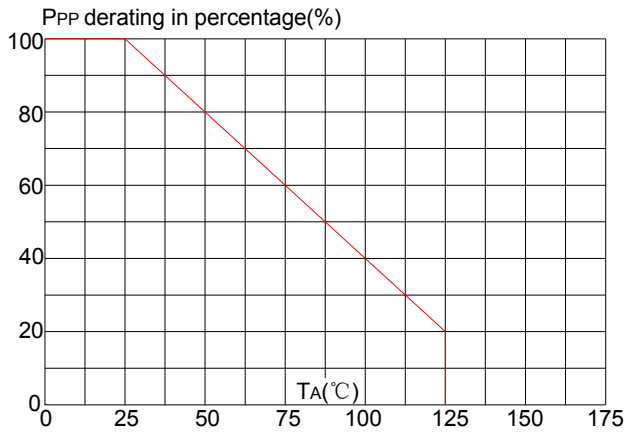
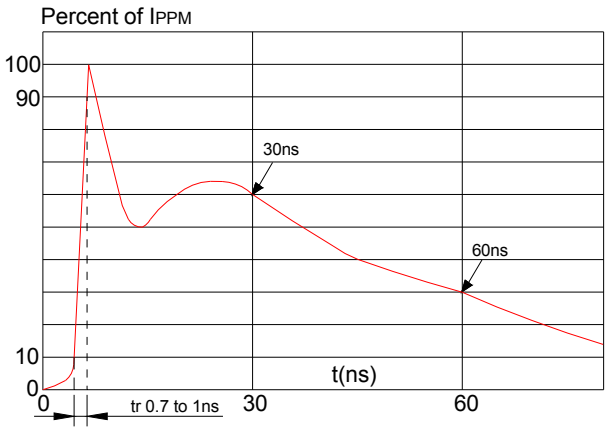
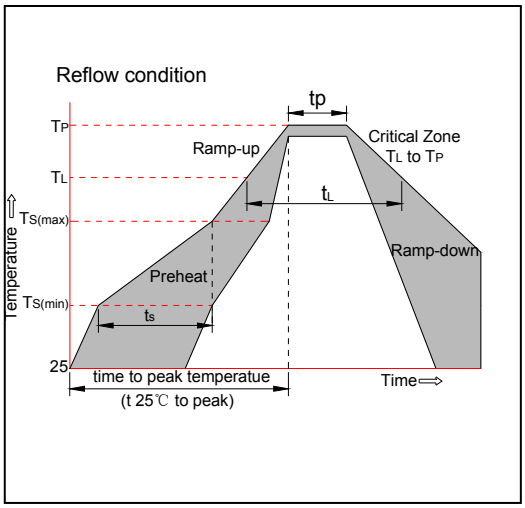


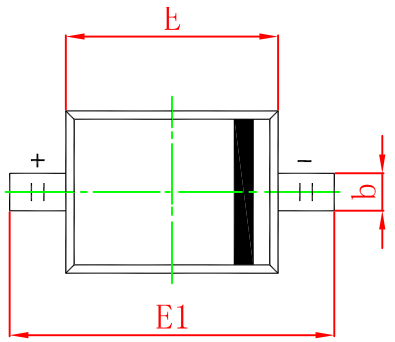
FIG.4: ESD clamping (30kV contact)

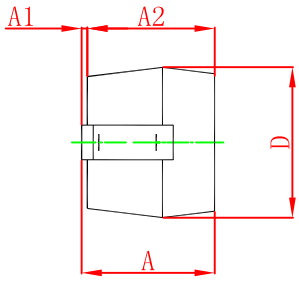


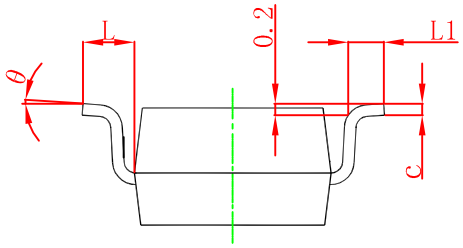
SOLDERING PARAMETERS

Reflow Condition		Pb-Free assembly (see figure at right)
Pre Heat	-Temperature Min ($T_{s(min)}$)	+150℃
	-Temperature Max($T_{s(max)}$)	+200℃
	-Time (Min to Max) (ts)	60-180 secs.
Average ramp up rate (Liquidus Temp (T_L)to peak)		3℃/sec. Max
$T_{s(max)}$ to T_L - Ramp-up Rate		3℃/sec. Max
Reflow	-Temperature(T_L)(Liquidus)	+217℃
	-Temperature(t_L)	60-150 secs.
Peak Temp (T_p)		+260(+0/-5)℃
Time within 5℃of actual Peak Temp (t_p)		20-40secs.
Ramp-down Rate		6℃/sec. Max
Time 25℃ to Peak Temp (T_P)		8 min. Max
Do not exceed		+260℃



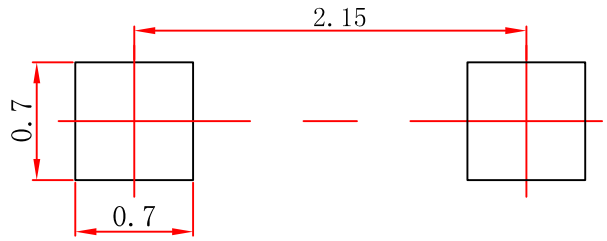






Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A		1.000		0.039
A1	0.000	0.100	0.000	0.004
A2	0.800	0.900	0.031	0.035
b	0.250	0.350	0.010	0.014
c	0.080	0.150	0.003	0.006
D	1.200	1.400	0.047	0.055
E	1.600	1.800	0.063	0.071
E1	2.550	2.750	0.100	0.108
L	0.475 REF.		0.019 REF.	
L1	0.250	0.400	0.010	0.016
θ	0°	8°	0°	8°

SOD-323 Suggested Pad Layout



Note:
1.Controlling dimension:in millimeters.
2.General tolerance:±0.05mm.
3.The pad layout is for reference purposes only.